# THE INVERSE OBSTACLE PROBLEM FOR NONLINEAR INCLUSIONS

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**Abstract**. The Monotonocity Principle states a monotonic relationship between a possibly non-linear material property and a proper corresponding boundary operator. The Monotonicity Principle (MP) has attracted great interest in the field of inverse problems, because of its fundamental role in developing real time imaging methods. Recently, with quite general assumptions, a MP in the presence of non linear materials has been established for elliptic PDE, such as those governing Electrical Resistance Tomography.

Together with recently introduced imaging methods and algorithms based on MP, arises a fundamental question related to the Converse (of the MP). Indeed, the Converse of the MP is fundamental to define the theoretical limits of applicability of imaging methods and algorithms. Specifically, the Converse of the MP guarantees that the outer boundary of a nonlinear anomaly can be reconstructed by means of MP based imaging methods.

In this paper, the Converse of the Monotonicity Principle for nonlinear anomaly embedded in a linear material is proved. The results is provided in a quite general setting for Electrical Resistance Tomography. Moreover, the nonlinear electrical conductivity of the anomaly, as function of the electric field, can be either bounded or not bounded from infinity and/or zero.

*Keywords:* Inverse obstacle problem, Nonlinear material, Monotonicity Principle, Converse.

# 1. INTRODUCTION

The development of real-time imaging algorithms is of great interest in electromagnetic tomography. Despite of their relevance in applications, very few of them are available for diverse implementations.

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Imaging methods based on Monotonicity Principle fall in the class of noniterative imaging methods. Colton and Kirsch introduced the first non-iterative approach named Linear Sampling Method (LSM) [9] followed by the Factorization Method (FM) proposed by Kirsch [29]; Ikehata proposed the Enclosure Method (EM) [25, 26, 27] and Devaney applied MUSIC (Multiple SIgnal Classification), a well known algorithm in signal processing, as imaging method [14].

In this framework of real-time imaging methods, a key role is played by the Monotonicity Principle, that states a monotonic relationship between the pointwise value of the spatial distribution of the material property and a proper boundary operator [19, 44]. In the case of Electrical Resistance Tomography (ERT) in the presence of nonlinear materials, the material property is the electrical conductivity, whereas the boundary operator is the so-called average Dirichlet-to-Neumann (ADtN) operator [11], a suitable generalization of the classical Dirichletto-Neumann operator to nonlinear cases.

Monotonicity based imaging methods for linear materials find applications in a wide range of problems modeled by different PDEs, from static (elliptic PDEs) to wave propagation (hyperbolic) problem, including quasi-static (parabolic) cases. The Monotonicity Principle Method (MPM) has first been proposed in [44] for ERT, a problem governed by an elliptic PDE, and developed for static problems such as Electrical Capacitance Tomography and Inductance Tomography, as well as Electrical Resistance Tomography [7, 16, 17, 46]. Then, it has been extended to quasi-static regimes governed by elliptic-parabolic PDEs [41], such as Eddy Current Tomography. In the latter case, MPM was proved for Eddy Current Tomography in the low-frequency (large skin-depth) limit [45], in the high-frequency (small skin-depth) limit [49] and in time domain (Pulsed Eddy Current Tomography) operations [38, 39, 40, 43, 47, 48].

Other extensions of the Monotonicity Principle can be found in [1, 2, 3, 13, 20, 22, 32, 42] for the Helmholtz equation, in [15] for linear elasticity equations and in [28] for the quasilinear generalizations of the classical biharmonic operator.

Finally, in [11] and [10], the Monotonicity Principle has been introduced for nonlinear problems, under quite general assumptions on the material property. The related imaging method, together with realistic numerical examples, can be found in [33].

Before introducing the Monotonicity Principle in this setting (ERT), it is proper to briefly state the targeted inverse problem and the governing equations for ERT. Specifically, the inverse problem in Electrical Resistance Tomography consists in reconstructing the spatial behaviour of the unknown electrical conductivity of a conductive medium, by means of DC (direct current) measurements carried out on the boundary of the domain of interest. The imaging problem treated in this contribution consists in retrieving the shape, position and dimension of unknown inclusions in a known background (the inverse obstacle problem). The governing equations for the underlying (nonlinear PDE) problem are those of steady (electrical) currents:

$$\begin{cases} \nabla \cdot \left( \sigma_{BG}(x) \nabla \varphi_{\Omega \setminus A}(x) \right) = 0 & \text{in } \Omega \setminus A \\ \nabla \cdot \left( \sigma_{NL}\left( x, |\nabla \varphi_A(x)| \right) \nabla \varphi_A(x) \right) = 0 & \text{in } A \\ \varphi_{\Omega \setminus A}(x) = f(x) & \text{on } \partial \Omega & (1.1) \\ \sigma_{BG}(x) \partial_n \varphi_{\Omega \setminus A}(x) = \sigma_{AN}\left( x, |\nabla \varphi_A(x)| \right) \partial_n \varphi_A(x) & \text{on } \partial A \\ \varphi_{\Omega \setminus A}(x) = \varphi_A(x) & \text{on } \partial A, \end{cases}$$

where  $\Omega \subseteq \mathbb{R}^n$ ,  $n \ge 2$ , is a given open and bounded domain,  $A \Subset \Omega$  is the region occupied by the nonlinear anomalies (see Figure 1),



FIGURE 1. Considered geometry:  $\Omega$  is the open and bounded domain, the region A is given by two inclusions filled by a nonlinear conductor.

$$u_A = \begin{cases} \varphi_{\Omega \setminus A} & \text{in } \Omega \setminus A \\ \varphi_A & \text{in } A, \end{cases}$$

is the electrical scalar potential,

$$\sigma_A(x, |\nabla u_A(x)|) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash A \\ \sigma_{NL}(x, |\nabla \varphi_A(x)|) & \text{in } A, \end{cases}$$
(1.2)

is the electrical conductivity defined on the whole domain. Function  $u_A$  represents the solution of the problem (1.1) on  $\Omega$  as a whole, whereas  $\varphi_A$  and  $\varphi_{\Omega\setminus A}$  are the restriction of the solution to A and  $\Omega\setminus A$ , respectively. In equation (1.2)  $\sigma_{BG}$  is the linear electrical conductivity for the background material, whereas  $\sigma_{NL}$  is the nonlinear electrical conductivity for the anomaly occupying the unknown region A. Solutions  $u_A$ ,  $\varphi_A$  and  $\varphi_{\Omega\setminus A}$  and the applied boundary potential f belongs

to  $X_{\diamond}$ , an appropriate abstract space (see Section 2 for details). The existence and uniqueness of the solution is guaranteed under suitable assumptions on the electrical conductivity  $\sigma_A$  (see Section 2).

MPM is a real-time imaging method which relies on the following monotone relation (see [11, 33] and [10] for details) connecting the unknown material property to the measured DtN or its inverse:

$$T \subseteq A \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A. \tag{1.3}$$

In (1.3) it has been assumed that  $\sigma_{NL}$  is greater than  $\sigma_{BG}$ , A and T are two subsets of  $\Omega$ , and  $\overline{\Lambda}_T \leq \overline{\Lambda}_A$  is intended as

$$\overline{\Lambda}_T \leqslant \overline{\Lambda}_A \iff \left\langle \overline{\Lambda}_T(f) - \overline{\Lambda}_A(f), f \right\rangle \leqslant 0 \quad \forall f$$

 $\overline{\Lambda}_A$  and  $\overline{\Lambda}_T$  are the *average* DtN operators defined as (see [11] and [10]):

$$\overline{\Lambda}_A : f \in X_\diamond \to \int_0^1 \Lambda_A(\alpha f) \, d\alpha \in X'_\diamond, \qquad \overline{\Lambda}_T : f \in X_\diamond \to \int_0^1 \Lambda_T(\alpha f) \, d\alpha \in X'_\diamond,$$
(1.4)

where

$$\Lambda_A : f \in X_\diamond \to \sigma_A \partial_n u_A |_{\partial\Omega} \in X'_\diamond, \qquad \Lambda_T : f \in X_\diamond \to \sigma_T \partial_n u_T |_{\partial\Omega} \in X'_\diamond$$
(1.5)

are the classical DtN operators related to anomalies occupying regions A and T, respectively.

In equations (1.3), (1.4) and (1.5)  $\overline{\Lambda}_A$ ,  $\Lambda_A$  and  $u_A$  refer to the electrical conductivity  $\sigma_A$  defined in (1.2), whereas  $\overline{\Lambda}_T$ ,  $\Lambda_T$  and  $u_T$  refer to the electrical conductivity  $\sigma_T$  given by

$$\sigma_T(x, E) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash T \\ \sigma_{NL}(x, E) & \text{in } T. \end{cases}$$

The imaging method is based on the following equivalent form of (1.3):

$$\overline{\Lambda}_T \leqslant \overline{\Lambda}_A \Longrightarrow T \nsubseteq A. \tag{1.6}$$

Relation (1.6) allows to infer when a test domain T is not included in the unknown anomaly A, starting from boundary data. From the monotonicity test of (1.6), a reconstruction method can be obtained by repeating the test for a set of test domains  $\{T_k\}$ , covering the region of interest, i.e. the estimate  $\tilde{A}$  of the inclusion A is

$$\widetilde{A} = \bigcup_{k \in \Theta} T_k$$

$$\Theta = \{ T_k \mid \overline{\Lambda}_A - \overline{\Lambda}_{T_k} \ge 0 \}.$$
(1.7)

It is worth noting that relationship (1.6) constitutes a sufficient condition to infer when  $T \not\subseteq A$ . In this contribution, we develop the converse of the Monotonicity Principle, i.e. we prove that  $\overline{\Lambda}_T \leq \overline{\Lambda}_A$  is necessary condition for  $T \subseteq A$ , i.e.

$$T \not\subseteq A \Longrightarrow \Lambda_A \leqslant \Lambda_T,$$

under the condition of A having a connected complement. This complements the results obtained so far for Electrical Resistance Tomography in the presence of non-linear materials [10, 11, 33].

Equations (1.3) and (1.6), give

$$T \subseteq A \Longleftrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A,$$

which has a relevant impact from both the theoretical and practical (algorithms' development) point of view. It allows to establish the theoretical limit of an imaging methods based on Monotonicity Principle. The converse has been proven in [23] for linear anomalies in a linear background. This work generalizes the results to nonlinear inclusions.

The study of inverse problems involving nonlinear Maxwell's equation arose only in recent years. According to our awareness, there are very only few works this research topic, as clearly stated in [31]: "... the mathematical analysis for inverse problems governed by nonlinear Maxwell's equations is still in the early stages of development.".

Despite of this general lack of results, there are many practical fields where nonlinear electrical conductivities are relevant. Superconductive materials, for example, present a strongly nonlinear electrical conductivity, often modelled by the so called *E-J Power Law* [34]. They are used in high energy storage, low-resistance energy transmission and in nuclear fusion (superconductive magnets) [30, 37]. Another relevant example is the termination of high voltage cables, where a Zinc-Oxide composite material with a nonlinear electrical conductivity is inserted at the end of the cable, to control the electric field [35]. The human tissues also are characterized by nonlinear electrical conductivity, as it appears in electroporation [50].

With reference to electrical resistance tomography, understood as a prototype problem for all phenomena modelled by Laplace equation, some results for the p-Laplacian, i.e. when the electrical conductivity is of the type

$$\sigma(x, E) = \theta(x)E^{p-2}$$

are available. Specifically, the inverse problem of retrieving p-Laplacian electrical conductivity from boundary measurements was first posed in [36], where the authors prove that the value of electrical conductivity on the boundary is uniquely determined by a nonlinear DtN operator. In [4] the authors extend the uniqueness result to the first order derivative. Furthermore, an inversion algorithm was given in [6], where the authors studied the enclosure method for the p-Laplacian to reconstruct the convex hull of an inclusion. In [5, 6, 21], an ad-hoc version of the Monotonicity Principle for the p-Laplacian was derived, and in [5] a Monotonicity Principle based reconstruction method for retrieving the complex hull of inclusions was proposed. For the sake of completeness, in [24] the properties of DtN operator, when  $\theta(x) = 1$ , are discussed, while in [12] the authors treat the

case of a non-linearity given by a linear term plus a p-Laplacian term and gave a procedure for reconstructing the electrical conductivity.

The paper is organized as follows. In Section 2 we give the mathematical foundations of the problem; in Section 3, we define the problem and recall some results on Monotonicity Principle for nonlinear electrical conductivity. In Section 4, we state our main results. This section is divided into four subsections in which we show the converse of the Monotonicity Principle with respect to different kind of nonlinearity. The conclusions are drawn in Section 5. In Appendix A and Appendix B are provided the proof of complementary results.

# 2. MATHEMATICAL FOUNDATIONS

Let  $\Omega \subseteq \mathbb{R}^n$ ,  $n \ge 2$ , be the region occupied by the conducting material. It is assumed that  $\Omega$  is an open bounded domain with a Lipschitz continuous boundary.

Let A be the unknown anomaly well contained in  $\Omega$ . It is required that A is an element of  $\mathcal{S}(\Omega)$ , where

 $\mathcal{S}(\Omega) := \{ V \subseteq \Omega : V \text{ is an open bounded set with a Lipschitz boundary } \}$ 

and  $\partial V$  is made by a finite number of connected components}.

Similarly, a generic test anomaly T is an element of  $\mathcal{S}(\Omega)$ .

This contribution is focused on a nonlinear inverse obstacle problem of great interest in applications, consisting in retrieving nonlinear anomalies embedded in a known linear background. The electrical conductivity representing the conductor is, therefore, given by

$$\sigma_A(x, E) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash A, \\ \sigma_{NL}(x, E) & \text{in } A, \end{cases}$$
(2.1)

where  $A \subset \Omega$  is the unknown region occupied by the nonlinear anomalies.

For isotropic conductors, electrical conductivity establishes the relationship between the amplitude of the electrical field  $\mathbf{E}$  and the amplitude of the electric current density field  $\mathbf{J}$ . From (2.1), it results that the constitutive relationship between the electric field and the electric current density is

$$\begin{cases} \mathbf{J}(x, E) = \sigma_{BG}(x) \mathbf{E}(x) & \text{in } \Omega \backslash A, \\ \mathbf{J}(x, E) = \sigma_{NL}(x, E) \mathbf{E}(x) & \text{in } A. \end{cases}$$
(2.2)

2.1. Assumptions. Before giving the assumptions on the electrical conductivity (2.1), it is convenient to recall the definition of the Carathéodory function.

**Definition 2.1.**  $\sigma: \Omega \times [0, +\infty) \to \mathbb{R}$  is a Carathéodory function in  $\Omega$  iff:

- $x \in \Omega \mapsto \sigma(x, E)$  is measurable for every  $E \in [0, +\infty)$ ,
- $E \in [0, +\infty) \mapsto \sigma(x, E)$  is continuous for almost every  $x \in \Omega$ .

We assume that  $\sigma_{BG} \in L^{\infty}_{+}(\Omega) = \{ u \in L^{\infty}(\Omega) : u \geq c_0 > 0 \text{ a.e. in } \Omega \}$  and  $\sigma_{NL} : A \times [0, +\infty) \to \mathbb{R}$  satisfies the following assumptions (see [10]):

- (A1)  $\sigma_{NL}$  is a Carathéodory function in  $\Omega$ ;
- (A2)  $E \in [0, +\infty) \mapsto \sigma_{NL}(x, E)E$  is strictly increasing for a.e.  $x \in A$ .
- (B1) There exist three positive constants  $\underline{\sigma} \leq \overline{\sigma}$  and  $E_0$  such that

 $\underline{\sigma} \leq \sigma_{NL}(x, E) \leq \overline{\sigma}$  for a.e.  $x \in A$  and  $\forall E > 0$ .

(B2) For fixed  $1 < q < +\infty$ , there exist three positive constants  $\underline{\sigma} \leq \overline{\sigma}$  and  $E_0$  such that

$$\underline{\sigma} \leqslant \sigma_{NL}(x, E) \leqslant \begin{cases} \overline{\sigma} \left[ 1 + \left( \frac{E}{E_0} \right)^{q-2} \right] & \text{if } q \ge 2, \\ \overline{\sigma} \left( \frac{E}{E_0} \right)^{q-2} & \text{if } 1 < q < 2 \end{cases}$$

for a.e.  $x \in \overline{A}$  and  $\forall E > 0$ .

(B3) For fixed  $2 \leq q < +\infty$ , there exist three positive constants  $\underline{\sigma} \leq \overline{\sigma}$  and  $E_0$  such that

$$\underline{\sigma}\left(\frac{E}{E_0}\right)^{q-2} \leqslant \sigma_{NL}(x, E) \leqslant \overline{\sigma}$$

for a.e.  $x \in \overline{A}$  and  $\forall E > 0$ .

(C1) There exists a constant  $\kappa > 0$  such that

$$(\sigma_{NL}(x, E_2)\mathbf{E}_2 - \sigma_{NL}(x, E_1)\mathbf{E}_1) \cdot (\mathbf{E}_2 - \mathbf{E}_1) \ge \kappa |\mathbf{E}_2 - \mathbf{E}_1|^2$$

for a.e.  $x \in A$  and for any  $\mathbf{E}_1, \mathbf{E}_2 \in \mathbb{R}^n$ .

(C2) For fixed  $1 < q < +\infty$ , there exists a constant  $\kappa > 0$  such that

$$(\sigma_{NL}(x, E_2)\mathbf{E}_2 - \sigma_{NL}(x, E_1)\mathbf{E}_1) \cdot (\mathbf{E}_2 - \mathbf{E}_1) \\ \geqslant \begin{cases} \kappa |\mathbf{E}_2 - \mathbf{E}_1|^q & \text{if } q \ge 2\\ \kappa (1 + |\mathbf{E}_2|^2 + |\mathbf{E}_1|^2)^{\frac{q-2}{2}} |\mathbf{E}_2 - \mathbf{E}_1|^2 & \text{if } 1 < q < 2 \end{cases}$$

for a.e.  $x \in A$  and for any  $\mathbf{E}_1, \mathbf{E}_2 \in \mathbb{R}^n$ .

(C3) For fixed  $2 \leq q < +\infty$ , there exists a constant  $\kappa > 0$  such that

$$(\sigma_{NL}(x, E_2)\mathbf{E}_2 - \sigma_{NL}(x, E_1)\mathbf{E}_1) \cdot (\mathbf{E}_2 - \mathbf{E}_1) \ge \kappa |\mathbf{E}_2 - \mathbf{E}_1|^q.$$

for a.e.  $x \in A$  and for any  $\mathbf{E}_1, \mathbf{E}_2 \in \mathbb{R}^n$ .

The above hypothesis take into account bounded as well as possibly unbounded or vanishing nonlinear electrical conductivity. Assumptions (A1) and (A2) hold for each case, while assumptions (BX) and (CX) are alternative each other. For the sake of clarity, Section 4 is divided in four subsection, considering different classes of non-linearity, since each class requires a different proof the (same) main result. Specifically, in Section 4.1 and 4.2 bounded, nonlinear electrical conductivity are considered, under assumptions (B1)-(C1); in Section 4.3 anomalies with possibly unbounded and nonlinear electrical conductivities are treated, under assumptions

(B2)-(C2); finally the case of nonlinear anomalies with possibly vanishing electrical conductivity is investigated in Section 4.4, under assumptions (B3)-(C3).

2.2. The mathematical model. From the physical standpoint, the mathematical model (1.1) follows by combining the constitutive relationship of (2.2), with  $\mathbf{E} = -\nabla u_A$ , being  $u_A$  a continuous function, and the solenoidality of J:

$$\begin{cases} \nabla \cdot \mathbf{J} = 0 \text{ in } \Omega \setminus A \\ \nabla \cdot \mathbf{J} = 0 \text{ in } A \\ \mathbf{J} \cdot \hat{\mathbf{n}} \quad \text{continuous across } \partial A. \end{cases}$$
(2.3)

In the mathematical model (1.1) the prescribed Dirichlet data f is an element of

$$X_{\diamond} = \left\{ g \in H^{1/2}(\partial\Omega) : \int_{\partial\Omega} g \, dS = 0 \right\}$$

and  $\partial_{\nu}$  denotes the outer normal derivative on  $\partial\Omega$ . Let us observe that  $\varphi_{\Omega\setminus A}$  belongs to  $H^1(\Omega\setminus A)$ , while  $\varphi_A$  belongs to  $H^1(A)$ ; so  $u_A$  belongs to a larger functional space  $H^1(\Omega)$ .

Problem (1.1) is understood in the weak form, i.e.

$$\int_{\Omega \setminus A} \sigma_{BG}(x) \nabla \varphi_{\Omega \setminus A}(x) \cdot \nabla \psi(x) \, dx + \int_A \sigma_{NL}(x, \nabla \varphi_A(x)) \nabla \varphi_A(x) \cdot \nabla \psi(x) \, dx = 0$$
(2.4)

for any  $\psi \in C_0^{\infty}(\Omega)$ . The unique weak solution  $u_A$  of the problem (2.4) is variationally characterized as

$$u_A = \arg\min\left\{\mathbb{E}_A(u) : u \in H^1(\Omega), \ u|_{\partial\Omega} = f \in X_\diamond\right\}.$$
(2.5)

The functional  $\mathbb{E}_A$  to be minimized is the Dirichlet Energy

$$\mathbb{E}_A(u) := \int_{\Omega} \int_0^{|\nabla u(x)|} \sigma_A(x,\eta) \eta \, d\eta \, dx.$$
(2.6)

Specifically, recalling (2.1), we have that

$$\mathbb{E}_{A}(u) = \int_{\Omega \setminus A} Q_{\sigma_{BG}}(x, |\nabla u(x)|) \, dx + \int_{A} Q_{\sigma_{NL}}(x, |\nabla u(x)|) \, dx$$

where

$$Q_{\sigma_{NL}}(x,E) = \int_0^E \sigma_{NL}(x,\eta)\eta \,d\eta \quad \text{for a.e. } x \in A \text{ and } \forall E \ge 0,$$
$$Q_{\sigma_{BG}}(x,E) = \frac{1}{2}\sigma_{BG}(x)E^2 \quad \text{for a.e. } x \in \Omega \backslash A \text{ and } \forall E \ge 0.$$

Existence and uniqueness of the solution of (2.4) is discussed in see [10].

We highlight that the average DtN operator is related to the Dirichlet Energy (see [11, 10]):

$$\left\langle \overline{\Lambda}_A(f), f \right\rangle = \mathbb{E}_A(u_A).$$
 (2.7)

2.3. **The DtN operator.** The Dirichlet-to-Neumann (DtN) operator maps the Dirichlet data into the corresponding Neumann data:

$$\Lambda_A : f \in X_\diamond \mapsto \sigma_A(x, |\nabla u_A|) \ \partial_n u_A|_{\partial\Omega} \in X'_\diamond,$$

where  $X'_{\diamond}$  is the dual space of  $X_{\diamond}$  and  $u_A$  is the solution of (1.1). From the physical standpoint, the DtN operator maps the boundary electric scalar potential into the normal component of the electrical current density entering  $\partial \Omega$ .

In weak form, the DtN operator is

$$\left\langle \Lambda_A\left(f\right),\psi\right\rangle = \int_{\partial\Omega} \psi(x)\sigma_A\left(x,\left|\nabla u_A(x)\right|\right)\partial_n u_A(x)\,\mathrm{d}S \quad \forall\psi\in X_\diamond.$$
(2.8)

Furthermore, by testing the DtN operator (2.8) with the solution u of (1.1) and using a divergence Theorem, we obtain the ohmic power dissipated by the conducting material:

$$\langle \Lambda_A(f), f \rangle = \int_{\Omega} \sigma_A(x, \nabla u_A(x)) |\nabla u_A(x)|^2 \, \mathrm{d}x.$$
 (2.9)

# 3. Statement of the Problem

In this section we state the main problem, that is the proof of the converse of (1.3) for the relevant case of electrical conductivities arising from two-phase materials, as in (2.1).

For the convenience of the reader, we remind the definition of outer support [23] of a set  $A \subseteq \Omega$ .

**Definition 3.1.** The outer support of a set  $A \subseteq \Omega$ , denoted as  $\operatorname{out}_{\partial\Omega} A$ , is the complement in  $\overline{\Omega}$ , of the union of those relatively open set U contained in  $\Omega \setminus \overline{A}$  and connected to  $\partial\Omega$ , i.e. those sets U that are connected and satisfying  $\partial U \cap \partial\Omega \neq \emptyset$ .

In the following, for the sake of simplicity, the outer support is denoted with a \* superscipt, i.e.

$$A^* \equiv \operatorname{out}_{\partial\Omega} A. \tag{3.1}$$

**Remark 3.2.** It is worth noting that all the boundary points of  $A^*$  are *connected* to  $\partial\Omega$ . Moreover, when A does not contain cavities, it results that

$$A^* = A, \tag{3.2}$$

refer also to Figure 2.

The Monotonicity Principle in (1.3) can be equivalently expressed as

$$\overline{\Lambda}_T \leqslant \overline{\Lambda}_A \Longrightarrow T \nsubseteq A. \tag{3.3}$$

Equation (3.3) is the foundation of the methods based on Monotonicity Principle. Indeed, as anticipated in the introduction, under the very general assumption that



FIGURE 2. Left: Anomaly A represented by a torus with a void inside. Center: outer support of A. Right: a set A, made by several connected components, that does not have any cavity and coincides with  $A^*$ .

the anomaly A can be expressed as

$$A = \bigcup_{T \in S_A} T, \tag{3.4}$$

where the Ts are open sets,  $S_A \subseteq \mathcal{P}(\Omega)$  and  $\mathcal{P}(\Omega)$  is the power set of  $\Omega$ , a reconstruction of A can be obtained as:

$$\tilde{A} = \bigcup_{T \in \Theta_A} T,$$
  
$$\Theta_A = \{T \in \mathcal{P}(\Omega) | \overline{\Lambda}_A - \overline{\Lambda}_T \ge 0\}$$

In other words, the monotonicity test of (3.3) allows to discard from the union those candidate sets (test anomalies) T that are surely not completely included in A.

**Remark 3.3.** It is worth noting that

$$A \subseteq \tilde{A}.\tag{3.5}$$

Indeed, if  $T \subseteq A$ , then from (1.3) it follows that T is an element of  $\Theta_A$ .

The main contribution of this work consists in proving that

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A. \tag{3.6}$$

Equation (3.6) gives a condition for exact reconstruction of A. Indeed, if A has a connected complement then the anomaly can be reconstructed without errors by the reconstruction rule presented above. In this sense, the converse of monotonicity in (3.6) states the limit of reconstruction methods based on Monotonicity Principle in presence of nonlinear materials. Specifically, if A has a connected complement we have

$$T \nsubseteq A \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A$$

and so

$$T \nsubseteq A \Longleftrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A.$$

# 4. Main result

Before stating the main result, the concept of localized potentials is extended from Neumann data [18] to Dirichlet data. Localized potentials have been exploited to prove the converse of the Monotonicity Principle in the linear case [23].

**Proposition 4.1.** Let  $S_1, S_2 \subset \Omega$  be two open sets such that  $\overline{S_1} \cap \overline{S_2} = \emptyset$  and  $\Omega \setminus (\overline{S_1} \cup \overline{S_2})$  is connected. Let the linear electrical conductivity  $\sigma \in L^{\infty}_+(\Omega)$  be piecewise analytic. Then there exists a sequence  $\{f_n\}_{n \in \mathbb{N}} \subset X_{\diamond}$  of boundary potentials such that the family of solutions  $\{u_n\}_{n \in \mathbb{N}}$  of the following steady current problem

$$\begin{cases} \nabla \cdot (\sigma(x)\nabla u_n(x)) = 0 & in \ \Omega, \\ u_n(x) = f_n(x) & on \ \partial\Omega, \end{cases}$$
(4.1)

fulfills

$$\lim_{n \to +\infty} \int_{S_1} \sigma(x) \left| \nabla u_n(x) \right|^2 \, dx = 0 \quad and \quad \lim_{n \to +\infty} \int_{S_2} \sigma(x) \left| \nabla u_n(x) \right|^2 \, dx = +\infty.$$

$$\tag{4.2}$$

**Remark 4.2.** It is worth noting that it is not mandatory for set  $S_2$  to coincide with its outer support, i.e.  $S_2$  is allowed to have cavities.

*Proof of Proposition 4.1.* The proof is based on the uniqueness of the solution for the Dirichlet problem and the existence of localized potentials for Neumann data [23, Theorem 3.6].

Let  $S_1, S_2 \subset \Omega$  be two open sets such that  $\overline{S_1} \cap \overline{S_2} = \emptyset$  and  $\Omega \setminus (\overline{S_1} \cup \overline{S_2})$  is connected. Following [23, Theorem 3.6], there exists a sequence  $\{g_n\}_{n \in \mathbb{N}} \subset X_{\diamond}$ such that the solutions  $v_n$  of the following steady currents problem

$$\begin{cases} \nabla \cdot (\sigma(x)\nabla v_n(x)) = 0 & \text{in } \Omega, \\ \sigma \partial_{\nu} v_n(x) = g_n(x) & \text{on } \partial \Omega, \\ \int_{\partial \Omega} v_n(x) \, dx = 0, \end{cases}$$
(4.3)

fulfill

$$\lim_{n \to +\infty} \int_{S_1} \sigma(x) \left| \nabla v_n(x) \right|^2 dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{S_2} \sigma(x) \left| \nabla v_n(x) \right|^2 dx = +\infty.$$
(4.4)

The Dirichlet data  $f_n \in X_{\diamond}$  gives  $u_n = v_n$  when plugged in problem (4.1) and, therefore, (4.4) implies (4.2).

In literature, some versions of localized potentials are present, with slightly different assumptions on  $S_1$  and  $S_2$ . In particular, in [18], it is required that  $\overline{S_1} \cap \overline{S_2} = \emptyset$  and  $\Omega \setminus (\overline{S_1} \cup \overline{S_2})$  is connected; in [23] it is introduced the notion of outer support for a set and the hypotheses become  $\mathring{S_2} \not \subseteq S_1^*$ . In [8], the localized

potentials are formulated as in the following: let  $U \subseteq \overline{\Omega}$  a relatively open set that intersect the boundary with a connected complement, let  $S_2 \subset U$  and let  $\sigma$  a linear piece-wise analytic electrical conductivity, then there exists a sequence  $\{g_n\}_{n\in\mathbb{N}} \subset X_{\diamond}$  such that the corresponding solutions  $\{u_n\}_{n\in\mathbb{N}}$  of the problem

$$\nabla \cdot (\sigma(x)\nabla u_n(x)) = 0$$
 in  $\Omega$  and  $\sigma(x)\partial_n u_n(x) = g_n(x)$  on  $\partial\Omega$ ,

fulfill

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx = 0 \quad \lim_{n \to +\infty} \int_{S_2} |\nabla u_n(x)|^2 \, dx = +\infty.$$
(4.5)

The same arguments of the proof of Proposition 4.1 can be applied indifferently to all these different formulations. In the following, we use some of these different formulations of localized potentials and, in doing that, we apply Proposition 4.1 to the particular formulation of interest.

For the sake of clarity, the remaining of the section is divided into four subsections in which it is shown the converse of the Monotonicity Principle, for different type of electrical conductivity for the nonlinear phase.

4.1. Anomalies more conductive than the background and with a bounded electrical conductivity. In this Section we consider  $\sigma_{NL}$  and  $\sigma_{BG}$  such that

$$\begin{cases} \sup_{\Omega \setminus A} \{ \sigma_{BG}(x) \} < \underline{\sigma} \\ 0 < \underline{\sigma} \leqslant \sigma_{NL}(x, E) \leqslant \overline{\sigma} < +\infty \quad \text{for a.e. } x \in A, \ \forall E > 0, \end{cases}$$
(4.6)

where  $\underline{\sigma}$  and  $\overline{\sigma}$  are two constants, defined in (B1). The second relationship in (4.6) is the assumption (B1) and, furthermore,  $\sigma_{NL}$  satisfy (A1), (A2) and (C1). In this case, the electrical conductivity of the anomaly is (i) greater than that of the background and (ii) is upper bounded. An example of nonlinear electrical conductivity compatible with conditions (4.6) is shown in Figure 3.

Given  $T \subset \Omega$ , we define the test electrical conductivity  $\sigma_T$  as

$$\sigma_T(x) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash T \\ \underline{\sigma} & \text{in } T. \end{cases}$$
(4.7)

The Figure 4 shows the unknown anomaly and the three possible cases of (i) the test anomaly T is completely contained into the exterior of the outer support of the unknown anomaly A ( $T \cap A^* = \emptyset$ ), (ii) the test anomaly T is partially contained in the outer support of A ( $T \not\subseteq A^*$ ) and ( $T \cap A^* \neq \emptyset$ ), and (iii) the test anomaly T is completely contained in the outer support of A ( $T \subseteq A^*$ ).

The following Theorem refers to the cases shown in Figure 4 (left) and (center).

**Theorem 4.3.** Let  $\sigma_{NL}$  satisfy (A1), (A2), (B1) and (C1), and  $\sigma_{BG}(x) \in L^{\infty}_{+}(\Omega)$  be piecewise analytic such that  $\sup_{\Omega \setminus A} \{\sigma_{BG}(x)\} < \underline{\sigma}$ . Let the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_T(x)$  be defined as in (2.1) and (4.7), respectively. Then,

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall A, T \in \mathcal{S}(\Omega). \tag{4.8}$$



FIGURE 3.  $\sigma_{NL}$  compatible with conditions in (4.6)



FIGURE 4. The three reference cases:  $T \cap A^* = \emptyset$  (left),  $T \not\subseteq A^*$ and  $T \cap A^* \neq \emptyset$  (center),  $T \subseteq A^*$  (right). For the sake of simplicity is assumed that  $A = A^*$ .

Moreover, if  $A \in \mathcal{S}(\Omega)$  has a connected complement, then

$$T \subseteq A \iff \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall \ T \in \mathcal{S}(\Omega).$$
 (4.9)

*Proof.* Let  $u_A$  and  $u_T$  be the weak solution of (1.1), with electrical conductivity equal to  $\sigma_A$  and  $\sigma_T$ , respectively.

It turns out that

$$\left\langle \overline{\Lambda}_A(f), f \right\rangle = \int_0^{|\nabla u_A(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx \leqslant \int_0^{|\nabla u_T(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx, \qquad (4.10)$$

where the first equality comes from (2.7) combined with (2.6), and the inequality comes from the minimality of  $u_A$  (see (2.5)). Hence,

$$\left\langle \overline{\Lambda}_A(f) - \overline{\Lambda}_T(f), f \right\rangle \leqslant \int_{\Omega} \int_0^{|\nabla u_T(x)|} \left( \sigma_A(x, \eta) - \sigma_T(x) \right) \eta \, d\eta \, dx, \tag{4.11}$$

where it has been exploited that  $\langle \overline{\Lambda}_T(f), f \rangle = \int_{\Omega} \int_0^{|\nabla u_T(x)|} \sigma_T(x) \eta \, d\eta \, dx$  (see (2.7) and (2.6), written for  $\sigma_T$ , rather than  $\sigma_A$ ).

In the following it is assumed that  $T \cap A^* \neq \emptyset$ . The case when  $T \cap A^*$  is empty, can be treated similarly by taking into account that the integrals over  $T \cap A^*$  disappear.

By substituting the expressions of  $\sigma_A$  and  $\sigma_T$  from (2.1) and (4.7) in (4.11), we have

$$\begin{split} \langle \overline{\Lambda}_A(f) - \overline{\Lambda}_T(f), f \rangle &\leq \int_{A^* \setminus T} \int_0^{|\nabla u_T(x)|} \left( \sigma_{NL}(x, \eta) - \sigma_{BG}(x) \right) \eta \, d\eta \, dx \\ &+ \int_{A^* \cap T} \int_0^{|\nabla u_T(x)|} \left( \sigma_{NL}(x, \eta) - \underline{\sigma} \right) \eta \, d\eta \, dx \\ &- \int_{T \setminus A^*} \int_0^{|\nabla u_T(x)|} \left( \underline{\sigma} - \sigma_{BG}(x) \right) \eta \, d\eta \, dx \\ &\leq \int_{A^* \setminus T} \int_0^{|\nabla u_T(x)|} \left( \overline{\sigma} - \sigma_{BG}(x) \right) \eta \, d\eta \, dx \\ &+ \int_{A^* \cap T} \int_0^{|\nabla u_T(x)|} \left( \overline{\sigma} - \underline{\sigma}_{BG}(x) \right) \eta \, d\eta \, dx \\ &- \int_{T \setminus A^*} \int_0^{|\nabla u_T(x)|} \left( \underline{\sigma} - \sigma_{BG}(x) \right) \eta \, d\eta \, dx \end{split}$$

and, therefore,

$$\langle \overline{\Lambda}_{A}(f) - \overline{\Lambda}_{T}(f), f \rangle \leq \frac{1}{2} \int_{A^{*} \setminus T} \left( \overline{\sigma} - \sigma_{BG}(x) \right) \left| \nabla u_{T}(x) \right|^{2} dx + \frac{1}{2} \int_{A^{*} \cap T} \left( \overline{\sigma} - \underline{\sigma} \right) \left| \nabla u_{T}(x) \right|^{2} dx - \frac{1}{2} \int_{T \setminus A^{*}} \left( \underline{\sigma} - \sigma_{BG}(x) \right) \left| \nabla u_{T}(x) \right|^{2} dx.$$

$$(4.12)$$

Let  $B_{\varepsilon}$  be a ball of radius  $\varepsilon > 0$  contained into the interior of  $T \setminus A^*$ , and let  $U \subseteq \overline{\Omega}$  be a relatively open, connected to  $\partial\Omega$  such that  $B_{\varepsilon} \subset U$ . From Proposition 4.1, there exists a sequence of boundary potentials  $\{f_n\}_{n\in\mathbb{N}} \subset X_{\diamond}$  such that the sequence of solutions  $\{u_n\}_{n\in\mathbb{N}}$  of the steady currents problem (4.1), with  $\sigma = \sigma_T$ , have the



FIGURE 5. Geometric relationships between sets  $\Omega$ , U, T,  $A^*$  and  $B_{\varepsilon}$ .

asymptotic behaviour (4.2) applied to  $S_1 = \Omega \backslash U$  and  $S_2 = B_{\varepsilon}$ 

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx = +\infty.$$

Consequently, it turns out that

$$\int_{A^* \setminus T} |\nabla u_n(x)|^2 \, dx \to 0, \tag{4.13}$$

$$\int_{A^* \cap T} \left| \nabla u_n(x) \right|^2 \, dx \to 0,\tag{4.14}$$

$$\int_{T \setminus A^*} |\nabla u_n(x)|^2 \, dx \ge \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx \to +\infty.$$
(4.15)

Therefore, by combining (4.12) for  $f = f_n$  and  $u_T = u_n$ , together with (4.13)-(4.15), it results that

$$\langle \overline{\Lambda}_A(f_n) - \overline{\Lambda}_T(f_n), f_n \rangle \to -\infty.$$

This proves that

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A. \tag{4.16}$$

When the outer support of A coincides with A, i.e.  $A^* = A$ , equation (4.16) combined with (1.3) gives the equivalence stated in (4.9).

4.2. Anomalies less conductive than background and with a bounded electrical conductivity. In this section we consider  $\sigma_{NL}$  and  $\sigma_{BG}$  be such that

$$\begin{cases} \overline{\sigma} < \inf_{\Omega \setminus A} \{ \sigma_{BG}(x) \} \\ 0 < \underline{\sigma} \leqslant \sigma_{NL}(x, E) \leqslant \overline{\sigma} < +\infty \quad \text{for a.e. } x \in A, \ \forall E > 0, \end{cases}$$
(4.17)

where  $\underline{\sigma}$  and  $\overline{\sigma}$  are two constants, defined in (B1). The second relationship in (4.17) is the assumption (B1) and, furthermore,  $\sigma_{NL}$  satisfy (A1), (A2) and (C1). In this case, the electrical conductivity of the anomaly is (i) smaller than that of the background and (ii) is lower bounded.

An example of nonlinear electrical conductivity compatible with conditions (4.17) is shown in Figure 6.



FIGURE 6.  $\sigma_{NL}$  compatible with conditions in (4.17)

Given an arbitrary test domain  $T \subset \Omega$ , the corresponding (test) electrical conductivity  $\sigma_T$  is defined as

$$\sigma_T(x) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash T \\ \overline{\sigma} & \text{in } T. \end{cases}$$
(4.18)

**Theorem 4.4.** Let  $\sigma_{NL}$  satisfy (A1), (A2), (B1) and (C1), and  $\sigma_{BG}(x) \in L^{\infty}_{+}(\Omega)$ be piecewise analytic such that  $\overline{\sigma} < \inf_{\Omega \setminus A} \{\sigma_{BG}(x)\}$ . Let the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_T(x)$  be defined as in (2.1) and (4.18), respectively. Then,

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall A, T \in \mathcal{S}(\Omega).$$

$$(4.19)$$

Moreover, if  $A \in \mathcal{S}(\Omega)$  has a connected complement, then for every  $T \subset \Omega$ ,

$$T \subseteq A \iff \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall \ T \in \mathcal{S}(\Omega).$$
 (4.20)

*Proof.* Let  $\sigma_A^I$  be the electrical conductivity defined as

$$\sigma_A^I(x) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash A \\ \underline{\sigma} & \text{in } A. \end{cases}$$
(4.21)

Since  $\sigma_A^I \leq \sigma_A$ , the Monotonicity Principle [10, 11] implies that  $\overline{\Lambda}_A^I \leq \overline{\Lambda}_A$ , being  $\overline{\Lambda}_A^I$  the DtN operator related to  $\sigma_A^I$ . By combining this latter inequality with (4.11), it follows that

$$\left\langle \overline{\Lambda}_{T}(f) - \overline{\Lambda}_{A}(f), f \right\rangle \leqslant \left\langle \overline{\Lambda}_{T}(f) - \overline{\Lambda}_{A}^{I}(f), f \right\rangle \leqslant \int_{\Omega} \int_{0}^{\left| \nabla u_{A}^{I}(x) \right|} \left( \sigma_{T}(x) - \sigma_{A}^{I}(x) \right) d\eta \, dx,$$

$$(4.22)$$

where  $u_A^I$  is the solution of a steady currents problem in the presence of the electrical conductivity  $\sigma_A^I$ 

$$\begin{cases} \nabla \cdot \left( \sigma_A^I(x) \nabla u_A^I(x) \right) = 0 & \text{ in } \Omega \\ u_A^I(x) = f(x) & \text{ on } \partial \Omega \end{cases}$$

In the following it is assumed that  $T \cap A^* \neq \emptyset$ . The case when  $T \cap A^*$  is empty, can be treated similarly by taking into account that the integrals over  $T \cap A^*$  disappear.

For  $T \cap A^* \neq \emptyset$ , by replacing  $\sigma_T$  and  $\sigma_A^I$  with their expressions (see (4.18) and (4.21)), it results that

$$\langle \overline{\Lambda}_{T}(f) - \overline{\Lambda}_{A}(f), f \rangle \leq \int_{A^{*} \setminus T} \left( \sigma_{BG}(x) - \underline{\sigma} \right) \left| \nabla u_{A}^{I}(x) \right|^{2} dx$$

$$+ \int_{A^{*} \cap T} \left( \overline{\sigma} - \underline{\sigma} \right) \left| \nabla u_{A}^{I}(x) \right|^{2} dx$$

$$- \int_{T \setminus A^{*}} \left( \overline{\sigma} - \sigma_{BG}(x) \right) \left| \nabla u_{A}^{I}(x) \right|^{2} dx.$$

$$(4.23)$$

Let  $B_{\varepsilon}$  be a ball of radius  $\varepsilon > 0$  contained into the interior of  $T \setminus A^*$ , and let  $U \subseteq \overline{\Omega}$  be a relatively open set, connected to  $\partial\Omega$  such that  $B_{\varepsilon} \subset U$  (see Figure 5).

From Proposition 4.1, there exists a sequence of boundary potentials  $\{f_n\}_{n\in\mathbb{N}} \subset X_{\diamond}$  such that the sequence of solutions  $\{u_n\}_{n\in\mathbb{N}}$  of the steady currents problem (4.1), with  $\sigma = \sigma_A^I$ , have the asymptotic behaviour (4.2) applied to  $S_1 = \Omega \setminus U$  and  $S_2 = B_{\varepsilon}$ 

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx = +\infty.$$

Consequently, it turns out that

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$$\int_{A^* \setminus T} |\nabla u_n(x)|^2 \, dx \to 0, \tag{4.24}$$

$$\int_{A^* \cap T} |\nabla u_n(x)|^2 \, dx \to 0, \tag{4.25}$$

$$\int_{T\setminus A^*} |\nabla u_n(x)|^2 \, dx \ge \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx \to +\infty.$$
(4.26)

Therefore, by combining (4.23) for  $f = f_n$  and  $u_A^I = u_n$ , together with (4.24)-(4.25)-(4.26), it results that

$$\langle \overline{\Lambda}_T(f_n) - \overline{\Lambda}_A(f_n), f_n \rangle \to -\infty.$$

This proves that

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \not \leqslant \overline{\Lambda}_A. \tag{4.27}$$

When the outer support of A coincides with A, i.e.  $A^* = A$ , equation (4.27) combined with (1.3) gives the equivalence stated in (4.20).

4.3. Anomalies more conductive than the background and with an unbounded electrical conductivity. In this section, we consider  $\sigma_{NL}$  satisfying (A1), (A2), (B2), (C2). For the convenience of the reader, we recall that accordingly to (B2), for fixed  $1 < q < +\infty$ , there exist three positive constants  $\underline{\sigma} \leq \overline{\sigma}$ and  $E_0$  such that

$$\underline{\sigma} \leqslant \sigma_{NL}(x, E) \leqslant \begin{cases} \overline{\sigma} \left[ 1 + \left( \frac{E}{E_0} \right)^{q-2} \right] & \text{if } q \ge 2, \\ \overline{\sigma} \left( \frac{E}{E_0} \right)^{q-2} & \text{if } 1 < q < 2, \end{cases}$$

$$(4.28)$$

for a.e.  $x \in \overline{A}$  and  $\forall E > 0$ . Furthermore,  $\sigma_{BG}$  fulfills

$$\sup_{\Omega \setminus A} \{\sigma_{BG}(x)\} < \underline{\sigma} \tag{4.29}$$

In this case, the electrical conductivity of the anomaly is (i) greater than that of the background and (ii) may be not upper bounded. An example of nonlinear electrical conductivity compatible with conditions (4.28) and (4.29) is shown in Figure 7.

**Remark 4.5.** Assumptions (4.28) control the growth rate of the electrical conductivity, i.e. the electrical conductivity can approach even to infinity but in a polynomial manner. The case  $q \ge 2$  is for electrical conductivities increasing with the amplitude of the electrical field  $(\sigma \to +\infty, \text{ for } E \to +\infty)$ . The case q < 2 takes into account for electrical conductivities decreasing with the amplitude of the electrical field  $(\sigma \to +\infty, \text{ for } E \to +\infty)$ . The case q < 2 takes into account for electrical conductivities decreasing with the amplitude of the electrical field  $(\sigma \to +\infty, \text{ for } E \to 0^+)$ . The case of electrical conductivity singular for a finite value of E does not fulfill (A2) (see Section 2.1) and, hence, is not covered by this work.



FIGURE 7.  $\sigma_{NL}$  compatible with conditions in (4.28) and (4.29)

However, it is worth noting that almost all practical cases are covered by the assumptions of this work.

Firstly, some definitions and lemmas are introduced. Specifically, the *average* DtN related to the electrical conductivity

$$\sigma_A^{\infty}(x) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash A \\ +\infty & \text{in } A. \end{cases}$$
(4.30)

is denoted as  $\overline{\Lambda}_A^{\infty}$ . The solution  $u_A^{\infty} \in H^1(\Omega)$  related to  $\sigma_A^{\infty}$  solves the problem

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x)\nabla u_A^{\infty}(x)) = 0 & \text{in } \Omega \backslash A \\ \nabla u_A^{\infty}(x) = 0 & \text{in } A \\ u_A^{\infty}(x) = f(x) & \text{on } \partial \Omega. \end{cases}$$
(4.31)

The following Lemmas (see Appendix A) provide crucial inequalities for treating perfectly conductive inclusions.

**Lemma 4.6.** Let  $\overline{\Lambda}_A$  and  $\overline{\Lambda}_A^{\infty}$  be the average DtN operators corresponding to the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_A^{\infty}(x)$ , defined in (2.1) and (4.30), respectively, under assumptions (4.29). Then, it results that

$$\overline{\Lambda}_A \leqslant \overline{\Lambda}_A^\infty.$$

**Lemma 4.7.** Let  $\Lambda_{BG}$  and  $\Lambda_A^{\infty}$  be the DtN operators related to the electrical conductivities  $\sigma_{BG}(x) \in L^{\infty}_{+}(\Omega)$  and  $\sigma_A^{\infty}(x)$  defined in (4.30). Assuming  $\sigma_{BG}(x)$  piecewise analytic and condition (4.29), there exists a positive constant K such that

$$0 \leq \langle \Lambda_A^{\infty}(f) - \Lambda_{BG}(f), f \rangle \leq K \int_A \left| \nabla u_{BG}(x) \right|^2 dx \qquad \forall f \in X_\diamond,$$

with  $u_{BG}$  solution of the steady currents problem

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla u_{BG}(x)) = 0 & \text{ in } \Omega \\ u_{BG}(x) = f(x) & \text{ on } \partial \Omega. \end{cases}$$

$$(4.32)$$

It is worth noting that the original steady current problem (1.1) reduces problem (4.32) when there are no anomalies  $(A = \emptyset)$ .

The proofs of Lemma 4.6 and Lemma 4.7 are provided in Appendix A. An inequality similar to that of Lemma 4.7 is available for the Neumann-to-Dirichlet operator in [8].

The following Theorem holds.

**Theorem 4.8.** Let  $\sigma_{NL}$  satisfy (A1), (A2), (B2) and (C2), and  $\sigma_{BG} \in L^{\infty}_{+}(\Omega)$  be piecewise analytic such that  $\sup_{\Omega \setminus A} \{\sigma_{BG}(x)\} < \underline{\sigma}$ . Let the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_T(x)$  be defined as in (2.1) and (4.7), respectively. Then,

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall A, T \in \mathcal{S}(\Omega).$$
(4.33)

Moreover, if  $A \in \mathcal{S}(\Omega)$  has a connected complement, then for every  $T \in \mathcal{S}(\Omega)$ ,

$$T \subseteq A \iff \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall \ T \in \mathcal{S}(\Omega).$$

$$(4.34)$$

*Proof.* From Lemma 4.6, it follows that

$$\langle \overline{\Lambda}_A(f) - \overline{\Lambda}_T(f), f \rangle \leq \langle \overline{\Lambda}_A^{\infty}(f) - \overline{\Lambda}_T(f), f \rangle$$

$$= \langle \overline{\Lambda}_A^{\infty}(f) - \overline{\Lambda}_{BG}(f), f \rangle - \langle \overline{\Lambda}_T(f) - \overline{\Lambda}_{BG}(f), f \rangle,$$

$$(4.35)$$

with  $\overline{\Lambda}_{BG}$  being the *average* DtN corresponding to electrical conductivity  $\sigma_{BG}$ .

The first term at the r.h.s. of (4.35) can be upper bounded as follows

$$\langle \overline{\Lambda}_{A}^{\infty}(f) - \overline{\Lambda}_{BG}(f), f \rangle = \frac{1}{2} \langle \Lambda_{A}^{\infty}(f) - \Lambda_{BG}(f), f \rangle \leqslant K_{1} \int_{A} |\nabla u_{BG}(x)|^{2} dx, \quad (4.36)$$

where the equality holds since both  $\overline{\Lambda}_{BG}$  and  $\overline{\Lambda}_{A}^{\infty}$  are associated to linear electrical conductivities, whereas the inequality follows Lemma 4.7.

The second term at the r.h.s. of (4.35), can be lower bounded as follows

$$\langle \overline{\Lambda}_{T}(f) - \overline{\Lambda}_{BG}(f), f \rangle = \frac{1}{2} \langle \Lambda_{T}(f) - \Lambda_{BG}(f), f \rangle$$

$$\geq \frac{1}{2} \int_{\Omega} \frac{\sigma_{BG}(x)}{\sigma_{T}(x)} (\sigma_{T}(x) - \sigma_{BG}(x)) |\nabla u_{BG}(x)|^{2} dx \qquad (4.37)$$

$$= \frac{1}{2} \int_{T} \frac{\sigma_{BG}(x)}{\underline{\sigma}} (\underline{\sigma} - \sigma_{BG}(x)) |\nabla u_{BG}(x)|^{2} dx,$$

where the first line holds because both  $\overline{\Lambda}_{BG}$  and  $\overline{\Lambda}_A^{\infty}$  are associated to linear electrical conductivities, the second line comes from [5, Lemma 2.1] for p = 2 (see also references therein) and, finally, the third line follows from the fact that  $\sigma_T$  and  $\sigma_{BG}$  agree on  $\Omega \setminus T$ .

By combining (4.35), (4.36) and (4.37), it results that

$$\left\langle \left(\overline{\Lambda}_{A}(f) - \overline{\Lambda}_{T}(f)\right), f \right\rangle \leqslant K_{1} \int_{A} \left| \nabla u_{BG}(x) \right|^{2} dx - \frac{1}{2} \int_{T} \frac{\sigma_{BG}(x)}{\underline{\sigma}} (\underline{\sigma} - \sigma_{BG}(x)) \left| \nabla u_{BG}(x) \right|^{2} dx.$$

$$(4.38)$$

Let  $B_{\varepsilon}$  be a ball of radius  $\varepsilon > 0$  contained into the interior of  $T \setminus A^*$ , and let  $U \subseteq \overline{\Omega}$  be a relatively open, connected to  $\partial \Omega$  such that  $B_{\varepsilon} \subset U$ .

From Proposition 4.1, there exists a sequence of boundary potentials  $\{f_n\}_{n\in\mathbb{N}} \subset X_\diamond$ such that the sequence of solutions  $\{u_n\}_{n\in\mathbb{N}}$  of the steady currents problem (4.1), with  $\sigma = \sigma_{BG}$ ,  $S_1 = \Omega \setminus U$ , and  $S_2 = B_\varepsilon$ , has the asymptotic behaviour

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx = +\infty.$$

Consequently, it turns out that

$$\int_{A} |\nabla u_n(x)|^2 \, dx \leq \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx \to 0, \tag{4.39}$$

$$\int_{T} \left| \nabla u_n(x) \right|^2 \, dx \ge \int_{B_{\varepsilon}} \left| \nabla u_n(x) \right|^2 \, dx \to +\infty. \tag{4.40}$$

Therefore, by combining (4.38) for  $f = f_n$  and  $u_{BG} = u_n$ , together with (4.39) and (4.40), it results that

$$\left\langle \left(\overline{\Lambda}_A(f_n) - \overline{\Lambda}_T(f_n)\right), f_n \right\rangle \to -\infty.$$

This proves that

$$T \not\subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A. \tag{4.41}$$

When the outer support of A coincides with A, i.e.  $A^* = A$ , equation (4.41) combined with (1.3) gives the equivalence stated in (4.34).

# 4.4. Anomalies less conductive than the background with possibly vanishing electrical conductivity. In this section we consider $\sigma_{NL}$ and $\sigma_{BG}$ be such that

$$\begin{cases} \overline{\sigma} < \inf_{\Omega \setminus A} \{ \sigma_{BG}(x) \} & \text{in } \Omega \setminus A \\ \underline{\sigma} \left( \frac{E}{E_0} \right)^{q-2} \leqslant \sigma_{NL}(x, E) \leqslant \overline{\sigma} & \text{for a.e. } x \in A, \ \forall E > 0, \end{cases}$$
(4.42)

where  $q \in [2, \infty)$  and  $\overline{\sigma}$ ,  $\underline{\sigma}$ ,  $E_0$  are three proper constants. The second relationship in (4.42) is the assumption (B3) and, furthermore,  $\sigma_{NL}$  satisfy (A1), (A2) and (C3). In this case, the electrical conductivity of the anomaly is (i) smaller than that of the background and (ii) may be vanishing. An example of nonlinear electrical conductivity compatible with conditions (4.42) is shown in Figure 8.



FIGURE 8.  $\sigma_{NL}$  compatible with conditions in (4.42)

In this case, let  $\overline{\Lambda}^0_A$  be the *average* DtN associated to the electrical conductivity

$$\sigma_A^0(x) = \begin{cases} \sigma_{BG}(x) & \text{in } \Omega \backslash A \\ 0 & \text{in } A. \end{cases}$$
(4.43)

Let  $u_A^0 \in H^1(\Omega)$  be the solution associated to the steady currents problem when the electrical conductivity is  $\sigma_A^0$  and the Dirichlet boundary data is f. Solution  $u_A^0$ , when restricted to  $\Omega \backslash A$ , solves

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla u_A^0(x)) = 0 & \text{in } \Omega \backslash A \\ \sigma_{BG}(x) \partial_{\nu} u_A^0(x) = 0 & \text{on } \partial A \\ u_A^0(x) = f(x) & \text{on } \partial \Omega, \end{cases}$$
(4.44)

whereas  $u_A^0$  restricted to A solves

$$\begin{cases} \Delta u_A^0(x) = 0 & \text{in } A\\ u_A^0(x) = g(x) & \text{on } \partial A, \end{cases}$$
(4.45)

being g the restriction to  $\partial A$  of the solution  $u_A^0$  of problem (4.44).

From the physical standpoint, we remind that the scalar potential  $u_A^0$  represents the electric field, via its gradient. System (4.44) corresponds to a steady current problem in  $\Omega \setminus A$ , being A impenetrable (non conducting) to the electrical current density. System (4.45) corresponds to an electrostatic problem in A. This latter system of PDEs requires the knowledge on  $\partial A$  of the solution  $u_A^0$  arising from (4.44).

The following Lemmas (see Appendix B for the proofs) provide crucial inequalities for treating perfectly conductive inclusions.

**Lemma 4.9.** Let  $\overline{\Lambda}_A$  and  $\overline{\Lambda}_A^0$  be the average DtN operators corresponding to the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_A^0(x)$ , defined in (2.1) and (4.43), respectively, under assumptions (4.42). Then, it results that

$$\overline{\Lambda}_A \geqslant \overline{\Lambda}_A^0.$$

**Lemma 4.10.** Let  $S_1, S_2 \subset \Omega$  be two open sets such that  $\Omega \setminus \overline{S_1}$  is connected,  $\partial S_1$  consists of a single connected component, and  $S_2 \subset \subset \Omega \setminus S_1^*$ . Let the linear electrical conductivity  $\sigma \in L^{\infty}_+(\Omega)$  be piece-wise analytic. Then there exists a sequence  $\{f_n\}_{n \in \mathbb{N}} \subset X_{\diamond}$  of boundary potentials such that the corresponding family of solutions  $\{u_n\}_{n \in \mathbb{N}}$  fulfills

$$\lim_{n \to +\infty} \int_{S_1} \sigma(x) \left| \nabla u_n(x) \right|^2 \, dx = 0 \quad and \quad \lim_{n \to +\infty} \int_{S_2} \sigma(x) \left| \nabla u_n(x) \right|^2 \, dx = +\infty,$$

where  $u_n$  is obtained with the electrical conductivity  $\sigma$  in  $\Omega \setminus S_1$  and a perfect insulating anomaly in  $S_1$ , i.e.  $u_n$  restricted to  $\Omega \setminus S_1$ , solves

$$\begin{cases} \nabla \cdot (\sigma(x) \nabla u_n(x)) = 0 & in \ \Omega \setminus S_1 \\ \sigma(x) \partial_{\nu} u_n(x) = 0 & on \ \partial S_1 \\ u_n(x) = f_n(x) & on \ \partial \Omega, \end{cases}$$
(4.46)

whereas  $\nu$  is the outer normal to  $S_1$  and  $u_n$  restricted to  $S_1$  solves

$$\begin{cases} \Delta u_n(x) = 0 & \text{in } S_1 \\ u_n(x) = g_n(x) & \text{on } \partial S_1, \end{cases}$$
(4.47)

being  $g_n$  the restriction to  $\partial S_1$  of the solution  $u_n$  of problem (4.46).

**Remark 4.11.** Lemma 4.10 can be generalized for  $\partial S_1$  consisting of multiple connected components and  $S_1$  made by either a single or multiple connected components. Specifically, let  $S_1$  be equal to  $S_1 = C_1 \cup C_2 \cup \cdots \cup C_m$ , being  $m \ge 1$ ,  $C_1, \ldots, C_m$  connected and disjoint. If  $C_i = C_i^*$ , for all  $i = 1, \ldots, m$ , then Lemma 4.10 holds without any modifications. If there exists  $C_i \ne C_i^*$ , then that there exists a connected component B of  $\Omega \setminus S_1$  that is not electrically connected to  $\partial\Omega$ . In this subset the electric field and the electrical current density are vanishing, therefore, it results that  $\sigma(x)\partial_{\nu}u_n = 0$ , on  $\partial B$ .

Here we state our main theorem regarding the converse of Monotonicity Principle, for the case of anomalies less conducting than the background. Anomalies, may also be perfectly insulating, i.e. with vanishing electrical conductivity. **Theorem 4.12.** Let  $\sigma_{NL}$  satisfy (A1), (A2), (B3) and (C3), and  $\sigma_{BG} \in L^{\infty}_{+}(\Omega)$  be piecewise analytic such that  $\sup_{\Omega \setminus A} \{\sigma_{BG}(x)\} > \overline{\sigma}$ . Let the electrical conductivities  $\sigma_A(x, E)$  and  $\sigma_T(x)$  be defined as in (2.1) and (4.18), respectively. Then,

$$T \not\subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall A, T \in \mathcal{S}(\Omega).$$
 (4.48)

Moreover, if  $A \in \mathcal{S}(\Omega)$  has a connected complement, then for every  $T \subset \Omega$ ,

$$T \subseteq A \iff \overline{\Lambda}_T \leqslant \overline{\Lambda}_A \qquad \forall \ T \in \mathcal{S}(\Omega).$$
 (4.49)

*Proof.* In the following it is assumed that  $T \cap A^* \neq \emptyset$ . The case when  $T \cap A^*$  is empty, can be treated similarly by deleting any integrals over  $T \cap A^*$ .

First of all, it is worth noting that

$$2\langle \overline{\Lambda}_{T}(f) - \overline{\Lambda}_{A}(f), f \rangle \leq \langle \Lambda_{T}(f) - \Lambda_{A}^{0}(f), f \rangle$$

$$= \int_{\Omega} \sigma_{T}(x) |\nabla u_{T}(x)|^{2} dx - \int_{\Omega} \sigma_{A}^{0}(x) |\nabla u_{A}^{0}(x)|^{2} dx$$

$$\leq \int_{\Omega} \left( \sigma_{T}(x) - \sigma_{A}^{0}(x) \right) |\nabla u_{A}^{0}(x)|^{2} dx$$

$$\leq \int_{A^{*} \setminus T} \sigma_{BG}(x) |\nabla u_{A}^{0}(x)|^{2} dx + \int_{A^{*} \cap T} \overline{\sigma} |\nabla u_{A}^{0}(x)|^{2} dx$$

$$- \int_{T \setminus A^{*}} \left( \sigma_{BG}(x) - \overline{\sigma} \right) |\nabla u_{A}^{0}(x)|^{2} dx \quad \forall f \in X_{\diamond}.$$

$$(4.50)$$

where in the first line we have exploited Lemma 4.9 and that the average DtN is one half of the "classical" DtN for linear materials (see (1.4)), in the second line we have used (2.9) written for both  $\sigma_T$  and  $\sigma_A^0$ , in the third line we have used the minimality of the Dirichlet Energy (see Subsection 2.2 for an electrical conductivity equal to  $\sigma_T$ , rather than  $\sigma_A$ ), in the last line we have exploited that

$$\sigma_{T}(x) - \sigma_{A}^{0}(x) \leqslant \begin{cases} 0 & \text{in } \Omega \setminus (T \cup A^{*}) \\ \sigma_{BG}(x) & \text{in } A^{*} \setminus T \\ \overline{\sigma} & \text{in } A^{*} \cap T \\ \overline{\sigma} - \sigma_{BG}(x) & \text{in } T \setminus A^{*}. \end{cases}$$

$$(4.51)$$

Let  $B_{\varepsilon}$  be a spherical neighborhood contained into the interior of  $T \setminus A^*$ , and let  $U \subseteq \overline{\Omega}$  be a relatively open, connected to  $\partial\Omega$  such that  $B_{\varepsilon} \subset U$  (see Figure 5). From Lemma 4.10, it follows that there exists a sequence of boundary potentials  $\{f_n\}_{n\in\mathbb{N}} \subset X_{\diamond}$  such that the sequence of extended solutions  $\{u_n\}_{n\in\mathbb{N}}$  of the steady current problem has the asymptotic behaviour

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla u_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx = +\infty.$$

Consequently, it turns out that

$$\int_{A^* \setminus T} |\nabla u_n(x)|^2 \, dx \to 0, \tag{4.52}$$

$$\int_{A^* \cap T} \left| \nabla u_n(x) \right|^2 \, dx \to 0,\tag{4.53}$$

$$\int_{T\setminus A^*} |\nabla u_n(x)|^2 \, dx \ge \int_{B_{\varepsilon}} |\nabla u_n(x)|^2 \, dx \to +\infty.$$
(4.54)

Therefore, by combining (4.50) for  $f = f_n$  and  $u_A^0 = u_n$ , together with (4.52)-(4.54), it results that

$$\langle \overline{\Lambda}_A(f_n) - \overline{\Lambda}_T(f_n), f_n \rangle \to -\infty.$$

This proves that

$$T \not \subseteq A^* \Longrightarrow \overline{\Lambda}_T \leqslant \overline{\Lambda}_A. \tag{4.55}$$

When the outer support of A coincides with A, i.e.  $A^* = A$ , equation (4.55) combined with (1.3) gives the equivalence stated in (4.49).

### 5. Conclusions

In this paper, we prove the converse of the Monotonicity Principle for electrical resistance tomography in presence of nonlinear materials, i.e.

$$T \subseteq A \iff \overline{\Lambda}_A \leqslant \overline{\Lambda}_T,$$

where T is a test domain and A is an unknown anomaly with a connected complement  $(A = A^*)$ . The converse has been proven in a special case of practical interest consisting of a nonlinear anomaly A embedded in a linear known background. The theoretical results holds also for a nonlinear electrical conductivity that is unbounded or vanishing.

The key idea is to reduce the problem to a linear one that can be analyzed by means of localized potentials for Dirichlet data.

The converse of Monotonicity Principle contributes to the development of the theoretical foundation of imaging methods in the presence of nonlinear materials, which are still at the early stage of development. In particular, it makes possible to extend the method developed for linear materials to nonlinear ones:

$$\tilde{A} = \bigcup_{k \in \Theta} T_k \text{ where } \Theta = \{T_k \mid \overline{\Lambda}_A - \overline{\Lambda}_{T_k} \ge 0\}.$$

where  $\tilde{A}$  is a reconstruction of the unknown anomaly A, and  $\{T_k\}$  is a set of test domains.

APPENDIX A. SHARP ESTIMATES FOR PERFECTLY CONDUCTING INCLUSIONS

In this Appendix, we provide the proof of Lemmas 4.6 and 4.7, essential in the development of Subsection 4.3.

Consider the nonlinear electrical conductivity  $\sigma_A$  defined as in (2.1). Let us recall that  $u_A$  is the solution of problem (1.1) with the electrical conductivity  $\sigma_A$  and the boundary data  $f \in X_{\diamond}$ . For a perfect electrically conducting (PEC) inclusions  $A \subset \Omega$ , the electrical conductivity  $\sigma_A^{\infty}$  is defined in (4.30) and the related scalar potential  $u_A^{\infty}$  is the solution of (4.31).

Proof of Lemma 4.6. We notice that  $u_A \in H^1(\Omega)$  is the unique minimizer of (2.6). As a consequence, we have

$$\begin{split} \langle \overline{\Lambda}_A(f), f \rangle &= \int_{\Omega} \int_0^{|\nabla u_A(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx \\ &\leqslant \int_{\Omega} \int_0^{|\nabla u_A^{\infty}(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx \\ &= \int_{\Omega \setminus A} \int_0^{|\nabla u_A^{\infty}(x)|} \sigma_{BG}(x) \eta \, d\eta \, dx = \langle \overline{\Lambda}_A^{\infty}(f), f \rangle \qquad \forall f \in X_\diamond, \end{split}$$

where it has been exploited that  $|\nabla u_A^{\infty}| = 0$  in A, the region where the electrical conductivity is infinite.

Proof of Lemma 4.7. Let us consider the variational problem

$$\min_{\substack{u \in H^1(\Omega \setminus A) \\ u_{|\partial\Omega} = 0 \\ u_{|\partialA} = u_{BG} - \overline{u_{BG}}}} \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla u(x)|^2 dx,$$
(A.1)

where  $u_{BG}$  is the solution of problem (4.32) and  $\overline{u_{BG}}$  is the average of  $u_{BG}$  on A. If  $w \in H^1(\Omega \setminus A)$  is the minimizer of (A.1), then it is the solution of

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla w(x)) = 0 & \text{in } \Omega \setminus A \\ w(x) = 0 & \text{on } \partial \Omega \\ w(x) = u_{BG}(x) - \overline{u}_{BG} & \text{on } \partial A. \end{cases}$$

By the inverse trace inequality, we know that there exists a constant  $C_1 > 0$ and  $g \in H^1(\Omega \setminus A)$  with  $\operatorname{Tr}(g) = 0$  on  $\partial\Omega$  and  $\operatorname{Tr}(g) = u_{BG} - \overline{u}_{BG}$  on  $\partial A$  such that  $||\nabla g||_{L^2(\Omega \setminus A)} \leq C_1 ||u_{BG} - \overline{u}_{BG}||_{H^{1/2}(\partial A)}.$ 

Therefore, we provide

$$\begin{split} \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla w(x)|^2 dx &\leq \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla g(x)|^2 dx \leq \underline{\sigma} \|g\|_{L^2(\Omega \setminus A)}^2 \\ &\leq \underline{\sigma} C_1 \|u_{BG} - \overline{u}_{BG}\|_{H^{1/2}(\partial A)}^2 \leq \underline{\sigma} C_1 C_2 \|u_{BG} - \overline{u}_{BG}\|_{H^1(A)}^2 \\ &\leq \underline{\sigma} C_1 C_2 \|\nabla u_{BG}\|_{L^2(A)}^2. \end{split}$$

where in the first inequality we have used the minimality of (A.1), in the third inequality we have used the upper bound for  $\sigma_{BG}$ , in the fourth inequality we have used the inverse trace inequality on  $\Omega \setminus A$ , in the fifth inequality, we have used the classical trace inequality with constant  $C_2 > 0$ , in the sixth inequality we have use the Poincaré-Wirtinger inequality with constant  $C_3 > 0$ .

Hence by setting  $K = \underline{\sigma}C_1C_2$ , we have

$$\int_{\Omega \setminus A} \sigma_{BG}(x) \left| \nabla w(x) \right|^2 \, dx \leqslant K \| \nabla u_{BG} \|_{L^2(A)}^2. \tag{A.2}$$

At his stage, let us observe that  $w = u_{BG} - v$  where  $v \in H^1(\Omega \backslash A)$  is the solution of

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x)\nabla v(x)) = 0 & \text{in } \Omega \backslash A, \\ v(x) = f(x) & \text{on } \partial \Omega, \\ v(x) = \overline{u}_{BG} & \text{on } \partial A. \end{cases}$$

It follows that

$$\int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla w(x)|^2 dx = \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla u_{BG}(x)|^2 dx + \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla v(x)|^2 dx - 2 \int_{\Omega \setminus A} \sigma_{BG}(x) \nabla u_{BG}(x) \cdot \nabla v(x) dx = \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla u_{BG}(x)|^2 dx + \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla v(x)|^2 dx + 2 \int_{\Omega \setminus A} \sigma_{BG}(x) \nabla u_{BG}(x) \cdot \nabla w(x) dx.$$
(A.3)

Furthermore, using the divergence Theorem, we get

$$\int_{\Omega \setminus A} \sigma_{BG}(x) \nabla w(x) \cdot \nabla u_{BG}(x) \, dx = \int_{\partial \Omega} w(x) \sigma_{BG}(x) \partial_{\nu} u_{BG}(x) \, dx + \int_{\partial A} w(x) \sigma_{BG}(x) \partial_{\nu} u_{BG}(x) \, dx,$$
(A.4)

where  $\partial_{\nu}$  is the normal derivative along the outer direction w.r.t.  $\Omega \setminus A$ .

On the other hand, since v is a constant on  $\partial A$ , w = 0 on  $\partial \Omega$ , A is well contained in  $\Omega$  and

$$\int_{\partial A} \sigma_{BG}(x) \partial_{\nu} u_{BG}(x) = 0,$$

then (A.4) becomes

$$\int_{\Omega \setminus A} \sigma_{BG}(x) \nabla w(x) \cdot \nabla u_{BG}(x) \, dx = \int_{\partial A} w(x) \sigma_{BG}(x) \partial_{\nu} u_{BG}(x) \, dx$$
$$= \int_{\partial A} u_{BG}(x) \sigma_{BG}(x) \partial_{\nu} u_{BG}(x) \, dx \qquad (A.5)$$
$$= -\int_{A} \sigma_{BG}(x) \left| \nabla u_{BG}(x) \right|^2 \, dx.$$

Combining (A.2), (A.3) and (A.5), we obtain

$$\int_{\Omega \setminus A} \sigma_{BG}(x) \left| \nabla v(x) \right|^2 dx - \int_{\Omega \setminus A} \sigma_{BG}(x) \left| \nabla u_{BG}(x) \right|^2 dx \leqslant K \| \nabla u_{BG} \|_{L^2(A)}^2.$$
(A.6)

Since  $u_A^{\infty}$  is solution of (4.31), it is also the unique minimizer of

$$\min_{\substack{u \in H^{1}(\Omega) \\ \nabla u = 0 \text{ in } A \\ u|_{\partial \Omega} = f}} \int_{\Omega \setminus A} \sigma_{BG}(x) \left| \nabla u(x) \right|^{2} dx,$$

then it results that

$$\int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla v(x)|^2 dx \ge \int_{\Omega \setminus A} \sigma_{BG}(x) |\nabla u_A(x)|^2 dx.$$
(A.7)

Therefore, by combining (A.6) and (A.7), we obtain that

$$(K_{1}+1)\int_{A}\sigma_{BG}(x)\left|\nabla u_{BG}(x)\right|^{2} dx \ge \int_{\Omega\setminus A}\sigma_{BG}(x)\left|\nabla u_{A}(x)\right|^{2} dx$$
$$-\int_{\Omega}\sigma_{BG}(x)\left|\nabla u_{BG}(x)\right|^{2} dx$$
$$=\langle\Lambda_{A}^{\infty}(f)-\Lambda_{BG}(f),f\rangle,$$

and the conclusion follows by the fact that  $\sigma_{BG} \in L^{\infty}_{+}(\Omega)$ .

# APPENDIX B. SHARP ESTIMATES FOR PERFECTLY INSULATING INCLUSIONS

In this Appendix, they are provided the proof of Lemmas 4.9 and 4.10, essential in the development of Subsection 4.4.

Consider a perfect electrical insulting (PEI) inclusion  $A \subset \Omega$ , with electrical conductivity given by  $\sigma_A^0$  defined as in (4.43), and  $u_A^0$  being the solution of (4.44).

Proof of Lemma 4.9. The solution  $u_A^0$  of (4.44) is the unique minimizer of

$$\min_{\substack{u \in H^1(\Omega \setminus A) \\ u|_{\partial\Omega} = f}} \int_{\Omega \setminus A} \int_0^{|\nabla u(x)|} \sigma_{BG}(x) \eta \, d\eta \, dx.$$
(B.1)

Furthermore, we observe that

$$\begin{split} \langle \overline{\Lambda}_A(f), f \rangle &= \int_{\Omega} \int_0^{|\nabla u_A(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx \\ &\geqslant \int_{\Omega \setminus A} \int_0^{|\nabla u_A(x)|} \sigma_A(x, \eta) \eta \, d\eta \, dx \\ &= \int_{\Omega \setminus A} \int_0^{|\nabla u_A(x)|} \sigma_{BG}(x) \eta \, d\eta \, dx \\ &\geqslant \int_{\Omega \setminus A} \int_0^{|\nabla u_A^0(x)|} \sigma_{BG}(x) \eta \, d\eta \, dx \\ &= \langle \overline{\Lambda}_A^0(f), f \rangle, \end{split}$$

where in the first line we have used the definition of the average DtN operator  $\overline{\Lambda}_A$ , in the second line we have used the fact the integral restricts on a smaller domain, in the third line we have used the definition of  $\sigma_A^0$  as in (4.43), in the fourth line we have used the minimality of problem (B.1) and in the fifth line we have used the definition of the average DtN operator  $\overline{\Lambda}_A^0$ .

Proof of Lemma 4.10. This proof is an adaptation of that of [8, Lemma 5.3].

Let  $w_n = v_n|_{\Omega \setminus S_1} - u_n|_{\Omega \setminus S_1} \in H^1(\Omega \setminus S_1)$  be the difference (in  $\Omega \setminus S_1$ ) between the voltage potential in the absence and in the presence of a perfect insulating anomaly in  $S_1$ , respectively, i.e.  $w_n$  is the solution of

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla w_n(x)) = 0 & \text{in } \Omega \backslash S_1, \\ w_n(x) = 0 & \text{on } \partial \Omega, \\ \sigma_{BG}(x) \partial_{\nu} w_n(x) = \sigma_{BG}(x) \partial_{\nu} v_n(x) & \text{on } \partial S_1, \end{cases}$$

where  $v_n$  solves

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla v_n(x)) = 0 & \text{in } \Omega, \\ v_n(x) = f_n(x) & \text{on } \partial \Omega \end{cases}$$

and  $u_n$ , restricted to  $\Omega \setminus S_1$ , solves problem (4.46).

Moreover,  $w_n$  solves the following variational problem

$$\min_{\substack{u \in H^1(\Omega \setminus S_1) \\ u_{|\partial\Omega} = 0 \\ \sigma_{BG}\partial_\nu u_{|\partialS_1} = \sigma_{BG}\partial_\nu v_{n_{|\partialS_1}}}} \int_{\Omega \setminus S_1} \sigma_{BG}(x) |\nabla u(x)|^2 dx. \tag{B.2}$$

Furthermore, recalling that  $S_2 \subset \subset \Omega \setminus S_1^*$  and  $S_1^*$  is the complement in  $\overline{\Omega}$  of the union of those relatively open set V contained in  $\Omega \setminus \overline{S}_1$  and connected to  $\partial \Omega$ , then it immediately follows that there exists a relatively open set  $U \subset \overline{\Omega}$  intersecting the boundary  $\partial \Omega$  and such that  $S_1^* \subset \Omega \setminus \overline{U}$  and  $S_2 \subset U$ .

# We have

$$\begin{split} \overline{\sigma} \, \|w\|_{H^{1/2}(\partial S_1)} \, \|\nabla w_n\|_{L^2(\Omega \setminus S_1)} &\leq C_1 \overline{\sigma} \, \|w\|_{H^1(\Omega \setminus S_1)} \, \|\nabla w_n\|_{L^2(\Omega \setminus S_1)} \\ &\leq C_1 C_2 \overline{\sigma} \, \|\nabla w_n\|_{L^2(\Omega \setminus S_1)}^2 \\ &\leq C_1 C_2 \int_{\Omega \setminus S_1} \sigma_{BG}(x) |\nabla w_n(x)|^2 dx \\ &= C_1 C_2 \int_{\partial(\Omega \setminus S_1)} w_n \sigma_{BG} \partial_{\nu} w_n dS \\ &= C_1 C_2 \int_{\partial S_1} w_n \sigma_{BG} \partial_{\nu} v_n dS \\ &\leq C_1 C_2 \, \|w_n\|_{H^{1/2}(\partial S_1)} \, \|\sigma_{BG} \partial_{\nu} v_n\|_{H^{-1/2}(\partial S_1)} \\ &\leq C_1 C_2 \, \|w_n\|_{H^{1/2}(\partial S_1)} \, \|\sigma_{BG} \partial_{\nu} v_n\|_{H^{-1/2}(\partial S_1 \cup (\partial \Omega \setminus \partial U))} \\ &\leq C_1 C_2 \, \|w_n\|_{H^{1/2}(\partial S_1)} \, \|\sigma_{BG} \nabla v_n\|_{L^2(\Omega \setminus (S_1 \cup U))} + \|\nabla \cdot (\sigma_{BG} \nabla v_n)\|_{L^2(\Omega \setminus (S_1 \cup U))}) \\ &= C_1 C_2 \, \|w_n\|_{H^{1/2}(\partial S_1)} \, \|\sigma_{BG} \nabla v_n\|_{L^2(\Omega \setminus (S_1 \cup U))}, \end{split}$$

where in the first line we have used the trace inequality with constant  $C_1$ , in the second line we have used the generalized Poincaré inequality with constant  $C_2$ , in the third line we have used the lower bound for  $\sigma_{BG}$ , in the fourth line we have used the divergence theorem, in the fifth line we have used that  $\sigma_{BG}\partial_n v_n = \sigma_{BG}\partial_n w_n$ on  $\partial S_1$ , in the sixth line we used the definition of operatorial norm in  $H^{-1/2}(\partial S_1)$ , in the seventh line we exploited the fact that the integral increases on bigger sets, in the eighth line we have used the fact that the trace of the normal component is a bounded map from  $H_{div}(\Omega \setminus (S_1 \cup U))$  to  $H^{-1/2}(\partial S_1 \cup (\partial \Omega \setminus \partial U))$  and, in the nineth line we have used the fact that  $\nabla \cdot (\sigma_{BG} \nabla v_n) = 0$  in  $\Omega \setminus (S_1 \cup U)$ . Refer to Figure 9 for the geometric details.



FIGURE 9. Geometric relationships between sets  $\Omega$ , U,  $S_1$  and  $S_2$ .

Hence, by setting  $K := \frac{C_1 C_2}{\overline{\sigma}}$ , we have

$$\|\nabla w_n\|_{L^2(\Omega\setminus S_1)} \leq K \|\sigma_{BG} \nabla v_n\|_{L^2(\Omega\setminus (S_1\cup U))}.$$
(B.3)

By (4.5), there exists a sequence of boundary potentials  $\{f_n\}_{n\in\mathbb{N}} \subset X_{\diamond}$  such that the solutions  $\{v_n\}_{n\in\mathbb{N}}$  of

$$\begin{cases} \nabla \cdot (\sigma_{BG}(x) \nabla v_n(x)) = 0 & \text{in } \Omega, \\ v_n(x) = f_n(x) & \text{on } \partial \Omega, \end{cases}$$

fulfill

$$\lim_{n \to +\infty} \int_{\Omega \setminus U} |\nabla v_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{S_2} |\nabla v_n(x)|^2 \, dx = +\infty.$$
(B.4)

From (B.3) and (B.4), it follows that  $||\nabla w_n||_{L^2(\Omega \setminus S_1)}$  converges to zero when the localized potentials are applied on the boundary. Furthermore, recalling that  $u_n = v_n|_{\Omega \setminus S_1} - w_n$ , it follows that the limiting behaviour of  $\nabla v_n$  coincides with the limiting behaviour of  $\nabla u_n$  on  $\Omega \setminus S_1$ . So

$$\lim_{n \to +\infty} \int_{\Omega \setminus (S_1 \cup U)} |\nabla u_n(x)|^2 \, dx = 0 \quad \text{and} \quad \lim_{n \to +\infty} \int_{S_2} |\nabla u_n(x)|^2 \, dx = +\infty.$$
(B.5)

In order to conclude, it remains to investigate the asymptotic behavior on  $S_1$ . Since  $u_n$  tends to zero in  $H^1(\Omega \setminus (S_1 \cup U))$ , by applying the trace theorem, we have that  $||u_n||_{H^{1/2}(\partial S_1)}$  tends to 0. Since  $u_n$  in  $S_1$  solves (4.47), then it solves

$$\min_{\substack{u \in H^1(\Omega \setminus S_1) \\ u_{|\partial S_1} = g_n}} \int_{\Omega \setminus S_1} |\nabla u(x)|^2 dx, \tag{B.6}$$

being  $g_n$  the restriction to  $\partial S_1$  of the solution  $u_n$  of problem (4.46).

By the inverse trace inequality, we know that there exists a constant C > 0and  $h \in H^1(S_1)$  with  $\operatorname{Tr}(h) = g_n$  on  $\partial S_1$  such that  $||\nabla h||_{L^2(S_1)} \leq C_1 ||u_n||_{H^{1/2}(\partial S_1)}$ . Therefore, by using the minimality of (B.6), it follows that

$$\int_{S_1} \sigma_{BG}(x) |\nabla u_n(x)|^2 \, dx \leq C_\infty \int_{S_1} |\nabla h(x)|^2 \, dx \leq C_\infty C_1 ||u_n||_{H^{1/2}(\partial S_1)}.$$

Since the last term tends to zero, we have that

$$\lim_{n \to +\infty} \int_{S_1} \sigma_{BG}(x) \left| \nabla u_n(x) \right|^2 \, dx = 0. \tag{B.7}$$

The conclusion follows by joining (B.5) and (B.7).

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### AUTHORSHIP CONTRIBUTION STATEMENT

**A. Corbo Esposito, A. Tamburrino**: Conceptualization, Methodology, Formal analysis, Writing, Supervision.

L. Faella, V. Mottola, G. Piscitelli, R. Prakash: Conceptualization, Methodology, Formal analysis, Writing.

### DATA AVAILABILITY STATEMENT

No new data were created or analysed in this study.

### References

- A. ALBICKER AND R. GRIESMAIER, Monotonicity in inverse obstacle scattering on unbounded domains, Inverse Problems, 36 (2020), p. 085014.
- [2] —, Monotonicity in inverse scattering for maxwell's equations, Inverse Problems and Imaging, 17 (2023), pp. 68–105.
- [3] T. ARENS, R. GRIESMAIER, AND R. ZHANG, Monotonicity-based shape reconstruction for an inverse scattering problem in a waveguide, Inverse Problems, 39 (2023), p. 075009.
- [4] T. BRANDER, Calderón problem for the p-Laplacian: First order derivative of conductivity on the boundary, Proceedings of the American Mathematical Society, 144 (2014).
- [5] T. BRANDER, B. HARRACH, M. KAR, AND M. SALO, Monotonicity and enclosure methods for the p-Laplace equation, SIAM Journal on Applied Mathematics, 78 (2018), pp. 742–758.
- [6] T. BRANDER, M. KAR, AND M. SALO, Enclosure method for the p-Laplace equation, Inverse Problems, 31 (2015), p. 045001.
- [7] F. CALVANO, G. RUBINACCI, AND A. TAMBURRINO, Fast methods for shape reconstruction in electrical resistance tomography, NDT & E International, 46 (2012), pp. 32–40.
- [8] V. CANDIANI, J. DARDÉ, H. GARDE, AND N. HYVÖNEN, Monotonicity-based reconstruction of extreme inclusions in electrical impedance tomography, SIAM J. Math. Anal., 52 (2020), pp. 6234–6259.
- [9] D. COLTON AND A. KIRSCH, A simple method for solving inverse scattering problems in the resonance region, Inverse Problems, 12 (1996), p. 383.
- [10] A. CORBO ESPOSITO, L. FAELLA, V. MOTTOLA, G. PISCITELLI, R. PRAKASH, AND A. TAMBURRINO, *Piecewise nonlinear materials and monotonicity principle*, Inverse Problems, 40 (2024), pp. 1–31.
- [11] A. CORBO ESPOSITO, L. FAELLA, G. PISCITELLI, R. PRAKASH, AND A. TAMBURRINO, Monotonicity principle in tomography of nonlinear conducting materials, Inverse Problems, 37 (2021).
- [12] C. I. C¢RSTEA AND M. KAR, Recovery of coefficients for a weighted p-laplacian perturbed by a linear second order term, Inverse Problems, 37 (2020), p. 015013.
- [13] T. DAIMON, T. FURUYA, AND R. SAIIN, The monotonicity method for the inverse crack scattering problem, Inverse Problems in Science and Engineering, 28 (2020), pp. 1570–1581.
- [14] A. J. DEVANEY, Super-resolution processing of multi-static data using time reversal and music. Northeastern University preprint.
- [15] S. EBERLE AND B. HARRACH, Shape reconstruction in linear elasticity: standard and linearized monotonicity method, Inverse Problems, 37 (2021), p. 045006.
- [16] H. GARDE, Simplified reconstruction of layered materials in eit, Applied Mathematics Letters, 126 (2022), p. 107815.

- [17] H. GARDE AND N. HYVÖNEN, Reconstruction of singular and degenerate inclusions in calderón's problem, Inverse Problems and Imaging, 16 (2022), pp. 1219–1227.
- [18] B. GEBAUER, Localized potentials in electrical impedance tomography, Inverse Problems & Imaging, 2 (2008), pp. 251–269.
- [19] D. G. GISSER, D. ISAACSON, AND J. C. NEWELL, Electric current computed tomography and eigenvalues, SIAM Journal on Applied Mathematics, 50 (1990), pp. 1623–1634.
- [20] R. GRIESMAIER AND B. HARRACH, Monotonicity in inverse medium scattering on unbounded domains, SIAM Journal on Applied Mathematics, 78 (2018), pp. 2533–2557.
- [21] C.-Y. GUO, M. KAR, AND M. SALO, Inverse problems for p-laplace type equations under monotonicity assumptions, Rend. Istit. Mat. Univ. Trieste, 48 (2016).
- [22] B. HARRACH, V. POHJOLA, AND M. SALO, Dimension bounds in monotonicity methods for the helmholtz equation, SIAM Journal on Mathematical Analysis, 51 (2019), pp. 2995–3019.
- [23] B. HARRACH AND M. ULLRICH, Monotonicity-Based Shape Reconstruction in Electrical Impedance Tomography, SIAM Journal on Mathematical Analysis, 45 (2013), pp. 3382– 3403.
- [24] D. HAUER, The p-dirichlet-to-neumann operator with applications to elliptic and parabolic problems, Journal of Differential Equations, 259 (2015).
- [25] M. IKEHATA, How to draw a picture of an unknown inclusion from boundary measurements. two mathematical inversion algorithms, Journal of Inverse and Ill-Posed Problems, 7 (1999), pp. 255–272.
- [26] M. IKEHATA, On reconstruction in the inverse conductivity problem with one measurement, Inverse Problems, 16 (2000), pp. 785–793.
- [27] M. IKEHATA AND T. OHE, A numerical method for finding the convex hull of polygonal cavities using the enclosure method, Inverse Problems, 18 (2002), p. 111.
- [28] M. KAR, J. RAILO, AND P. ZIMMERMANN, The fractional p-biharmonic systems: optimal poincarà © constants, unique continuation and inverse problems, Calculus of Variations and Partial Differential Equations, 62 (2023), p. 130.
- [29] A. KIRSCH, Characterization of the shape of a scattering obstacle using the spectral data of the far field operator, Inverse Problems, 14 (1998), p. 1489.
- [30] G. KRABBES, G. FUCHS, W.-R. CANDERS, H. MAY, AND R. PALKA, High temperature superconductor bulk materials: fundamentals- processing- properties control- application aspects, Wiley-VCH Verlag, 2006.
- [31] K. F. LAM AND I. YOUSEPT, Consistency of a phase field regularisation for an inverse problem governed by a quasilinear maxwell system, Inverse Problems, 36 (2020), p. 045011.
- [32] H. MEFTAHI, Uniqueness, lipschitz stability, and reconstruction for the inverse optical tomography problem, SIAM Journal on Mathematical Analysis, 53 (2021), pp. 6326–6354.
- [33] V. MOTTOLA, A. CORBO ESPOSITO, G. PISCITELLI, AND A. TAMBURRINO, Imaging of nonlinear materials via the monotonicity principle, Inverse Problems, 40 (2024), p. 035007.
- [34] J. RHYNER, Magnetic properties and ac-losses of superconductors with power law currentvoltage characteristics, Physica C: Superconductivity, 212 (1993), pp. 292–300.
- [35] B. S, H. M, A. S, AND H. M, Interest of nonlinear zno/silicone composite materials in cable termination, Material Sci & Eng. 2018, 2(3) (2018).
- [36] M. SALO AND X. ZHONG, An inverse problem for the p-Laplacian: Boundary determination, SIAM Journal on Mathematical Analysis, 44 (2012), pp. 2474–2495.
- [37] P. SEIDEL, Applied Superconductivity: Handbook on Devices and Applications, Encyclopedia of Applied Physics, Wiley-VCH, 1 ed., 2015.
- [38] Z. SU, L. UDPA, G. GIOVINCO, S. VENTRE, AND A. TAMBURRINO, Monotonicity principle in pulsed eddy current testing and its application to defect sizing, in 2017 International

Applied Computational Electromagnetics Society Symposium - Italy (ACES), 2017, pp. 1–2.

- [39] Z. SU, L. UDPA, AND A. TAMBURRINO, Monotonicity of the transfer function for eddy current tomography, IEEE Sensors, 23 (2023), pp. 29156–291661.
- [40] Z. SU, S. VENTRE, L. UDPA, AND A. TAMBURRINO, Monotonicity based imaging method for time-domain eddy current problems, Inverse Problems, 33 (2017), p. 125007.
- [41] A. TAMBURRINO, Monotonicity based imaging methods for elliptic and parabolic inverse problems, Journal of Numerical Mathematics, 14 (2006), pp. 633–642.
- [42] A. TAMBURRINO, L. BARBATO, D. COLTON, AND P. MONK, Imaging of dielectric objects via monotonicity of the transmission eigenvalues, in abstracts book of the 12th International Conference on Mathematical and Numerical Aspects of Wave Propagation (Germany), 2015, pp. 99–100.
- [43] A. TAMBURRINO, G. PISCITELLI, AND Z. ZHOU, The monotonicity principle for magnetic induction tomography, Inverse Problems, 37 (2021).
- [44] A. TAMBURRINO AND G. RUBINACCI, A new non-iterative inversion method for electrical resistance tomography, Inverse Problems, 18 (2002), pp. 1809–1829.
- [45] A. TAMBURRINO AND G. RUBINACCI, Fast methods for quantitative eddy-current tomography of conductive materials, IEEE Transactions on Magnetics, 42 (2006), pp. 2017–2028.
- [46] A. TAMBURRINO, G. RUBINACCI, M. SOLEIMANI, AND W. R. B. LIONHEART, Non iterative inversion method for electrical resistance, capacitance and inductance tomography for two phase materials, in Proc. 3rd World Congress on Industrial Process Tomography, Canada, 2003.
- [47] A. TAMBURRINO, Z. SU, N. LEI, L. UDPA, AND S. UDPA, The monotonicity imaging method for pect, Studies in Applied Electromagnetics and Mechanics, 40 (2015), pp. 159– 166.
- [48] A. TAMBURRINO, Z. SU, S. VENTRE, L. UDPA, AND S. S. UDPA, Monotonicity based imaging method in time domain eddy current testing, Studies in Applied Electromagnetics and Mechanics, 41 (2015), pp. 1–8.
- [49] A. TAMBURRINO, S. VENTRE, AND G. RUBINACCI, Recent developments of a monotonicity imaging method for magnetic induction tomography in the small skin-depth regime, Inverse Problems, 26 (2010), p. 074016.
- [50] S. ČOROVIĆ, I. LACKOVIC, P. ŠUŠTARIČ, T. SUSTAR, T. RODIC, AND D. MIKLAVCIC, Modeling of electric field distribution in tissues during electroporation, Biomedical engineering online, 12 (2013), p. 16.